

SFT325 Transistor Datasheet. Parameters and Characteristics.

Type Designator: SFT325

Material of transistor: Ge

Polarity: pnp

Maximum collector power dissipation (P_c): 500mW

Maximum collector-base voltage (U_{cb}): 24V

Maximum collector-emitter voltage (U_{ce}): 16V

Maximum emitter-base voltage (U_{eb}): 12V

Maximum collector current (I_c max): 500mA

Maximum junction temperature (T_j): 85°C

Transition frequency (f_t): 1MHz

Collector capacitance (C_c), Pf:

Forward current transfer ratio (h_{FE}), min/max: 70T

Manufacturer of SFT325 transistor: MISTRAL

Package of SFT325 transistor: TO1